# N Channel MOSFET

# multicomp PRO

## RoHS Compliant



### Features

- V<sub>DS(V)</sub> = 150V
- I<sub>D</sub> = 70A
- R<sub>DS(on)</sub> 13mΩ (typ.) @ V<sub>GS</sub> = 10 V

#### Absolute Maximum Ratings (TA = 25°C unless otherwise noted)

Parameter		Symbol	Rating	Unit	
Drain-Source Voltage		Vds	150	V	
Gate-Source Voltage		Vgs	+20		
Continuous Drain Current	Tc = 25°C		70		
	Tc = 100°C	ID	49.5	A	
Pulsed Drain Current		Ідм	280		
Single Pulse Avalanche Energy (Note 1)		Eas	583	mJ	
Power Dissipation		Po	150	14/	
Thermal Resistance, Junction- to-Case (Note 2)		Rejc	0.83		
Junction Temperature		TJ	150	°C	
Storage Temperature Range		Tstg	-55 to 150		

Notes:

1. EAS condition : Tj=25°C,VDD=50V, VG=10V, L=0.5mH, Rg=25 $\Omega$ 

Surface Mounted on FR4 Board, t ≤ 10 sec. The value of RθJA is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with TA =25° C. the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.

#### Electrical Characteristics (TA = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BVdss	ID=-250µA, VGs=0V	150			V
Zero Gate Voltage Drain Current	Idss	VDS=-150V, VGS=0V			1	μA
Gate to Source Leakage Current	lgss	VDS=0V, VGS=±20V			±100	nA
On Characteristics (Note 3)						
Gate to Source Threshold Voltage	VGS(th)	VDS=VGS, ID=250µA	2		4	V
Static Drain-Source On-Resistance	RDS(On)	Vgs=10V, Id=35A		13	15	mΩ
Forward Transconductance	<b>g</b> FS	VDS=5V, ID=-35A		58		S
Dynamic Characteristics (Note 4)						
Input Capacitance	Ciss			2200		
Output Capacitance	Coss	Vgs=0V, Vbs=-75V, f=1MHz		289		pF
Reverse Transfer Capacitance	Crss			11.2		

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Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit
Switching Characteristics (Note 4)						
Total Gate Charge	Qg			33		
Gate Source Charge	Qgs	Vgs=10V, Vdd=75V, Id=-12A		14.5		nC
Gate Drain Charge	Qgd			8		
Turn-On DelayTime	td(on)			12.5		
Turn-On Rise Time	tr	Vgs = 10V, Vdd = 75V,		3.8		nS
Turn-Off DelayTime	td(off)	ID = 35A, RG = 3Ω		14		
Turn-Off Fall Time	tr			3.5		
Drain-Source Diode Characteristics						
Body Diode Reverse Recovery Time	trr	I⊧ = 35A, dI/dt = 100 A/µs,		47		nS
Body Diode Reverse Recovery Charge	Qrr	$T_J = 25^{\circ}C$		55		nC
Maximum Body-Diode Continuous Current	ls				70	А
Diode Forward Voltage (Note 3)	Vsd	V <sub>GS</sub> = 0 V, Is = 35 A			1.2	V

Notes:

3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$ 2%.

4. Guaranteed by design, not subject to production.

### **Typical Electrical and Thermal Characteristics**







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Figure 2 Transfer Characteristics







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## **Typical Characterisitics**







Figure 8 Safe Operation Area



Square Wave Pluse Duration(sec)
Figure 11 Normalized Maximum Transient Thermal Impedance



## Package Outline Dimensions



Symbol	Dimensions I	n Millimeters	<b>Dimensions In Inches</b>		
	Min.	Max.	Min.	Max.	
А	0.900	1.000	0.035	0.039	
A3	0.254	REF.	0.010	REF.	
D	4.944	5.096	0.195	0.201	
E	5.974	6.126	0.235	0.241	
D1	3.910	4.110	0.154	0.162	
E1	3.375	3.575	0.133	0.141	
D2	4.824	4.976	0.190	0.196	
E2	5.674	5.826	0.223	0.229	
k	1.190	1.390	0.047	0.055	
b	0.350	0.450	0.014	0.018	
е	1.270TYP.		0.050TYP.		
L	0.559	0.711	0.022	0.028	
L1	0.424	0.576	0.017	0.023	
Н	0.574	0.726	0.023	0.029	
θ	10°	12°	10°	12°	

Dimensions : Millimetres

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### Suggested Pad Layou



#### Notes

- 1. Controlling dimension: in millimeters.
- 2. General tolerance: ±0.05mm
- 3. The pad layout is for reference purposes only.

#### Diagram





### Part Number Table

	Description	Part Number
ensions : Millimetres	N Channel MOSFET, 70A, 150V	2KK6015DFN

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